



N-Channel 100-V (D-S) MOSFET

PRODUCT SUMMARY			
V _{(BR)DSS} (V)	r _{DS(on)} (Ω)	I _D (A)	
200	0.030 at V _{GS} = 10 V	65 ^a	

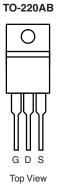
FEATURES

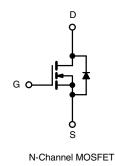
- TrenchFET[®] Power MOSFET
- 175 °C Junction Temperature
- Low Thermal Resistance Package
- 100 % Rg Tested

APPLICATIONS

• Isolated DC/DC Converters







ABSOLUTE MAXIMUM RATINGS	T _C = 25 °C, unless oth	erwise noted		
Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	100	v
Gate-Source Voltage		V _{GS}	± 20	v
Continuous Drain Current (T ₁ = 175 °C)	T _C = 25 °C	1-	65 ^a	
Continuous Drain Current $(1) = 175$ C)	T _C = 125 °C	I _D	37 ^a	A
Pulsed Drain Current		I _{DM}	140	^
Avalanche Current	L = 0.1 mH		35	
Single Pulse Avalanche Energy ^b		E _{AS}	61	mJ
Mariana Diata in Kat	T _C = 25 °C	Р	375 ^c	14/
Maximum Power Dissipation ^b	T _A = 25 °C ^d	– P _D –	3.75	- W
Operating Junction and Storage Temperature Range		T _J , T _{stq}	- 55 to 175	°C

THERMAL RESISTANCE RA	TINGS			
Parameter		Symbol	Limit	Unit
Junction-to-Ambient	PCB Mount (TO-263) ^d	R _{thJA}	40	°C/W
Junction-to-Case (Drain)		R _{thJC}	0.4	C/ W

Notes:

a. Package limited.

b. Duty cycle \leq 1 %.

c. See SOA curve for voltage derating.

d. When Mounted on 1" square PCB (FR-4 material).

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	$V_{DS} = 0 V, I_{D} = 250 \mu A$	100			v
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	2		4	v
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
		$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}$			1	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 100 V, V_{GS} = 0 V, T_{J} = 125 °C			50	μA
		$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$			250	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	120			Α
		V _{GS} = 10 V, I _D = 30 A		0.023	0.030	
Drain-Source On-State Resistance ^a	r _{DS(on)}	V_{GS} = 10 V, I _D = 30 A, T _J = 125 °C			0.063	Ω
		V_{GS} = 10 V, I _D = 30 A, T _J = 175 °C			0.084	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 30 A	25			S
Dynamic ^b	•					
Input Capacitance	C _{iss}			5100		pF
Output Capacitance	C _{oss}	$V_{GS} = 0 V$, $V_{DS} = 25 V$, f = 1 MHz		480		
Reverse Transfer Capacitance	C _{rss}			210		
Total Gate Charge ^c	Qg			90	130	nC
Gate-Source Charge ^c	Q _{gs}	V_{DS} = 100 V, V_{GS} = 10 V, I_{D} = 65 A		23		
Gate-Drain Charge ^c	Q _{gd}			34		
Gate Resistance	Rg		0.5	1.7	3.3	Ω
Turn-On Delay Time ^c	t _{d(on)}			24	35	
Rise Time ^c	t _r	V_{DD} = 100 V, R_L = 1.5 Ω		220	330	
Turn-Off Delay Time ^c	t _{d(off)}	$\rm I_D \cong 65$ A, $\rm V_{GEN}$ = 10 V, $\rm R_g$ = 2.5 Ω		45	70	ns
Fall Time ^c	t _f			200	300	
Source-Drain Diode Ratings and Cha	aracteristics 7	$\Gamma_{\rm C} = 25 \ ^{\circ}{\rm C}^{\rm b}$				
Continuous Current	ا _S				65	٨
Pulsed Current	I _{SM}				140	A
Forward Voltage ^a	V _{SD}	$I_{F} = 65 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$		1.0	1.5	V
Reverse Recovery Time	t _{rr}			130	200	ns
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = 50 A, di/dt = 100 A/μs		8	12	А
Reverse Recovery Charge	Q _{rr}			0.52	1.2	μC

Notes:

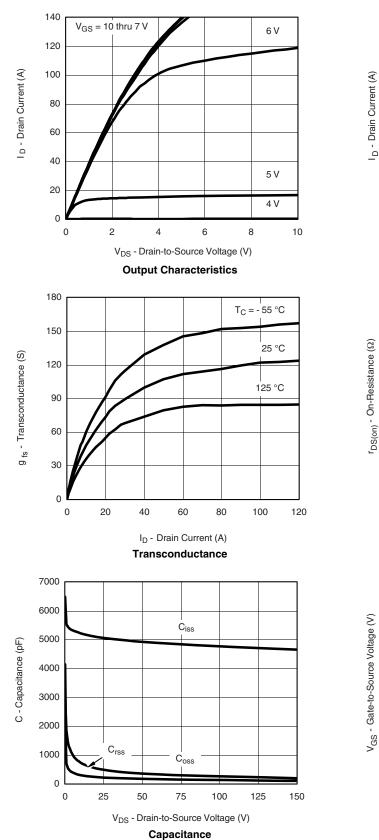
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

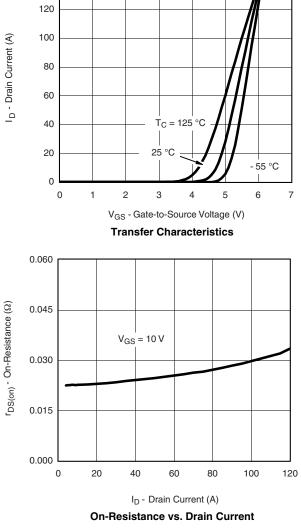
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

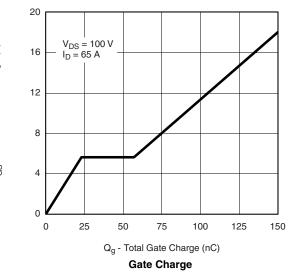
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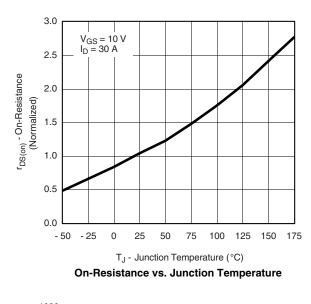
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

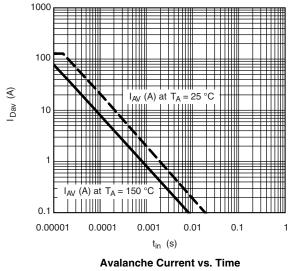


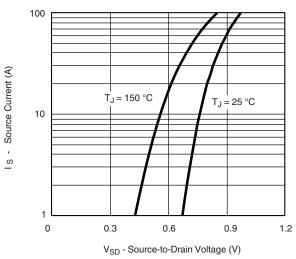
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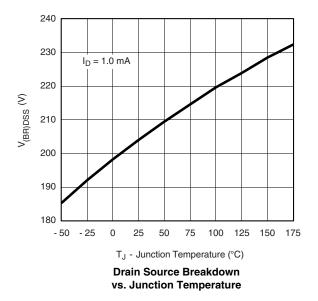
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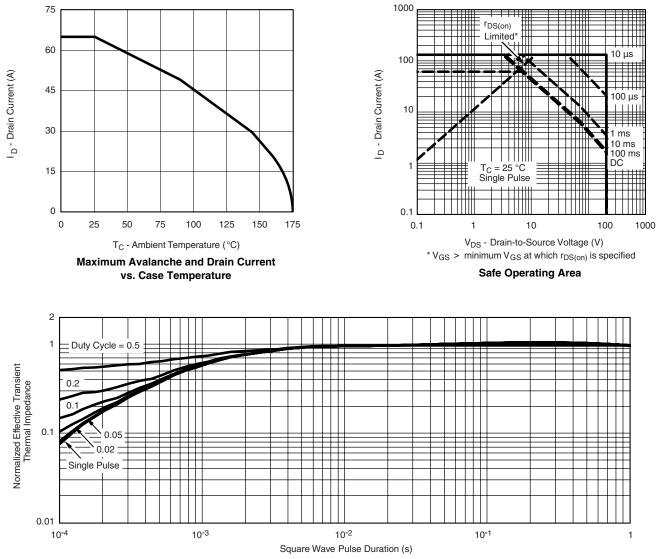
Source-Drain Diode Forward Voltage



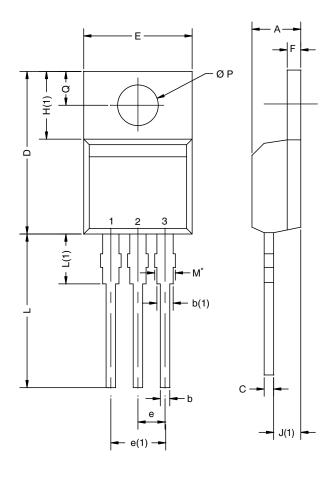
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THERMAL RATINGS



Normalized Thermal Transient Impedance, Junction-to-Case



TO-220AB

	MILLIMETERS		INC	HES
DIM.	MIN.	MAX.	MIN.	MAX.
А	4.25	4.65	0.167	0.183
b	0.69	1.01	0.027	0.040
b(1)	1.20	1.73	0.047	0.068
с	0.36	0.61	0.014	0.024
D	14.85	15.49	0.585	0.610
Е	10.04	10.51	0.395	0.414
е	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.09	6.48	0.240	0.255
J(1)	2.41	2.92	0.095	0.115
L	13.35	14.02	0.526	0.552
L(1)	3.32	3.82	0.131	0.150
ØР	3.54	3.94	0.139	0.155
Q	2.60	3.00	0.102	0.118
ECN: X12- DWG: 547	0208-Rev. N, 1	08-Oct-12		

Notes

 * M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM

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